VS-12CTQ035-M3, VS-12CTQ040-M3, VS12CTQ045-M3

**Vishay Semiconductors** 

## High Performance Schottky Rectifier, 2 x 6 A



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PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 6 A					
V <sub>R</sub>	35 V, 40 V, 45 V					
V <sub>F</sub> at I <sub>F</sub>	0.53 V					
I <sub>RM</sub> max.	7 mA at 125 °C					
T <sub>J</sub> max.	175 °C					
E <sub>AS</sub>	8 mJ					
Package	3L TO-220AB					
Circuit configuration	Common cathode					

#### FEATURES

- 175 °C T<sub>J</sub> operation
- Center tap TO-220 package
- · Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

The VS-12CTQ... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS VALUES V					
I <sub>F(AV)</sub>	Rectangular waveform	12	А			
V <sub>RRM</sub>	Range	35 to 45	V			
IFSM	t <sub>p</sub> = 5 μs sine	690	А			
V <sub>F</sub>	6 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.53	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-12CTQ035-M3	VS-12CTQ040-M3	VS-12CTQ045-M3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	35	40	45	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	55	40	40	v		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS					
Maximum average forward per leg			$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 160 °C, rectangular waveform		^			
current. See fig. 5 per device	I <sub>F(AV)</sub>	$50\%$ duty cycle at $1_{\rm C} = 100\%$	o, rectangular wavelonn	12	A			
Maximum peak one cycle non-repetitive	I <sub>FSM</sub>	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load	690	А			
surge current per leg. See fig. 7		10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	140				
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.20 A, L = 11.10 mH		8	mJ			
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.20	А			

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS			
		6 A	T. = 25 °C	0.60			
Maximum forward voltage drop per leg See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	12 A	1j=25 0	0.73	V		
	VFM (*)	6 A	T.I = 125 °C	0.53			
		12 A	1j = 125 C	0.64			
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	$T_J = 25 \ ^{\circ}C$		0.8	mA		
See fig. 2	IRM (')	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	7.0			
Threshold voltage	V <sub>F(TO)</sub>			0.35	V		
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		18.23	mΩ		
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal ran	400	pF			
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 n	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

#### Note

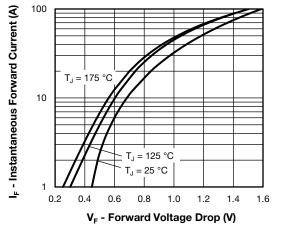
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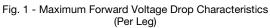
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	
Maximum thermal resistance junction to case per leg	,	R <sub>thJC</sub>	DC operation See fig. 4			
Maximum thermal resistance, junction to case per package		nthJC	DC operation	1.75	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Manustina tanan	minimum			6 (5)	kgf ⋅ cm	
Mounting torque maximum				12 (10)	(lbf ⋅ in)	
				12CT	Q035	
Marking device	Marking device		Case style 3L TO-220AB	12CT	Q040	
				12CT	Q045	

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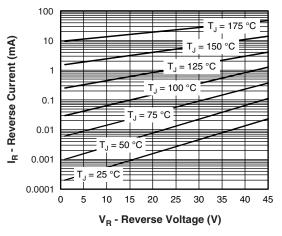


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

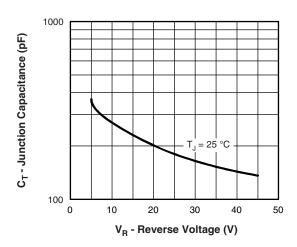


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

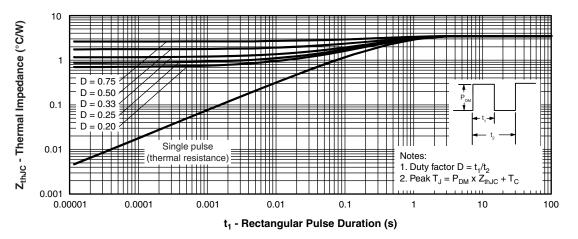
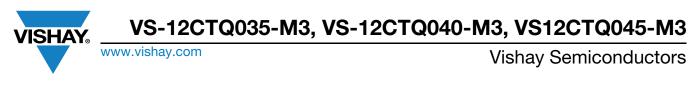
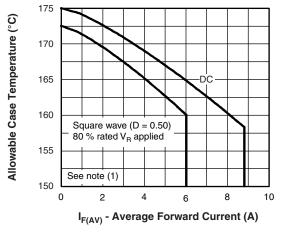
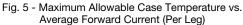


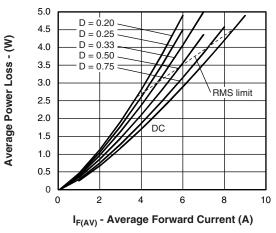
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

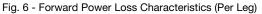
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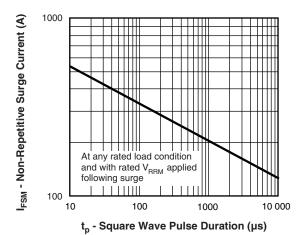


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

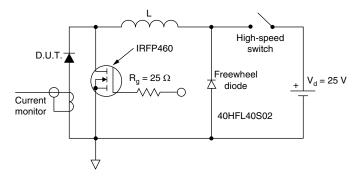


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd<sub>REV</sub> = inverse power loss =  $V_{R1} \times I_B$  (1 - D);  $I_B$  at  $V_{R1}$  = 80 % rated  $V_B$ 

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### **ORDERING INFORMATION TABLE**

Device code	vs-	12	с	т	Q	045	-M3		
		(2)	(3)	(4)	(5)	6	(7)		
	2 3 4 5	- Visl - Cur - Circ - C = - Pac T = - Sch	hay Sen rent rati cuit conf commo kage: TO-220	)" series	ctors pro = 12 A) n: de	U	035 = 3 040 = 4 045 = 4	0 V	
	7			ntal digit gen-free		ا complia-	ant, and	terminatior	n lead

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-12CTQ035-M3	50	1000	Antistatic plastic tube				
VS-12CTQ040-M3	50	1000	Antistatic plastic tube				
VS-12CTQ045-M3	50	1000	Antistatic plastic tube				

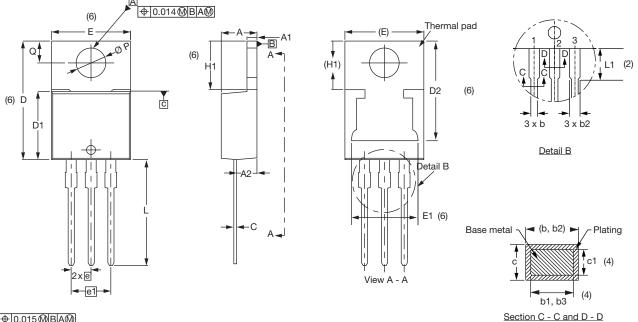
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96154				
Part marking information	www.vishay.com/doc?95028				
SPICE model	www.vishay.com/doc?95629				



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## **3L TO-220AB**

#### **DIMENSIONS** in millimeters and inches



⊕0.015@BA@





SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Ш	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

#### Notes

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

- <sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

Revision: 13-Jun-2019

 $<sup>^{(1)}\,</sup>$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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